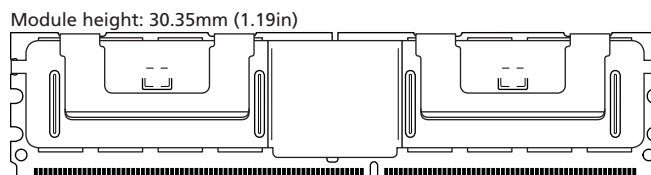


# DDR2 SDRAM FBDIMM

**MT36HTF25672FZ – 2GB**
**MT36HTF51272FZ – 4GB**

## Features

- DDR2 functionality and operations supported as defined in the component data sheet
- 240-pin, fully buffered dual in-line memory module (FBDIMM)
- Fast data transfer rates: PC2-6400, PC2-5300, or PC2-4200
- 2GB (256 Meg x 72), 4GB (512 Meg x 72)
- 3.2 Gb/s, 4 Gb/s, or 4.8 Gb/s link transfer rates
- High-speed, 1.5V differential, point-to-point link between the host controller and advanced memory buffer (AMB)
- Fault-tolerant; can work around a bad bit lane in each direction
- High-density scaling with up to eight FBDIMM devices per channel
- SMBus interface to AMB for configuration register access
- In-band and out-of-band command access
- Deterministic protocol
  - Enables memory controller to optimize DRAM accesses for maximum performance
  - Delivers precise control and repeatable memory behavior
- Automatic DDR2 SDRAM bus and channel calibration
- Transmitter de-emphasis to reduce intersymbol interference (ISI)

**Figure 1: 240-Pin FBDIMM (MO-256 R/C E)**


## Options

- Package
  - 240-pin DIMM (halogen-free)
- Frequency/CAS latency
  - 2.5ns @ CL = 5 (DDR2-800)
  - 3.0ns @ CL = 5 (DDR2-667)

## Marking

Z  
-80E  
-667

## Features (Continued)

- Mixed-signal built-in self-test (MBIST) and interrupt-driven built-in self-test (IBIST) test functions
- Transparent mode for DRAM test support
- $V_{DD} = V_{DDQ} = 1.8V$  for DRAM
- $V_{REF} = 0.9V$  SDRAM command and address termination
- $V_{CC} = 1.5V$  for AMB
- $V_{DDSPD} = 3-3.6V$  for AMB and EEPROM
- Serial presence-detect (SPD) with EEPROM
- Gold edge contacts
- Dual-rank
- Supports 95°C operation with 2X refresh

**Table 1: Key Timing Parameters**

| Speed Grade | Industry Nomenclature | Data Rate (MT/s) |        |        |        | $t_{RCD}$ (ns) | $t_{RP}$ (ns) | $t_{RC}$ (ns) |
|-------------|-----------------------|------------------|--------|--------|--------|----------------|---------------|---------------|
|             |                       | CL = 6           | CL = 5 | CL = 4 | CL = 3 |                |               |               |
| -80E        | PC2-6400              | 800              | 800    | 533    | 400    | 12.5           | 12.5          | 55            |
| -667        | PC2-5300              | –                | 667    | 533    | 400    | 15             | 15            | 55            |
| -53E        | PC2-4200              | –                | –      | 533    | 400    | 15             | 15            | 55            |



## 2GB, 4GB (x72, DR) 240-Pin DDR2 SDRAM FBDIMM Features

**Table 2: Addressing**

| Parameter                 | 2GB                 | 4GB               |
|---------------------------|---------------------|-------------------|
| Refresh count             | 8K                  | 8K                |
| Device bank address       | 4 BA[1:0]           | 8 BA[2:0]         |
| Device page size per bank | 1KB                 | 1KB               |
| Device configuration      | 512Mb (128 Meg x 4) | 1Gb (256 Meg x 4) |
| Row address               | 16K A[13:0]         | 16K A[13:0]       |
| Column address            | 2K A[11, 9:0]       | 2K A[11, 9:0]     |
| Module rank address       | 2 S#[1:0]           | 2 S#[1:0]         |

**Table 3: Part Numbers and Timing Parameters – 2GB**

Base device: MT47H128M4,<sup>1</sup> 512Mb DDR2 SDRAM

| Part Number <sup>2</sup> | Module Density | Configuration | Module Bandwidth | Memory Clock/<br>Data Rate | Clock Cycles<br>(CL- <sup>t</sup> RCD- <sup>t</sup> RP) | Link Transfer Rate |
|--------------------------|----------------|---------------|------------------|----------------------------|---------------------------------------------------------|--------------------|
| MT36HTF25672FZ-80E__     | 2GB            | 256 Meg x 72  | 6.4 GB/s         | 2.5ns/800 MT/s             | 5-5-5                                                   | 4.8 GT/s           |
| MT36HTF25672FZ-667__     | 2GB            | 256 Meg x 72  | 5.3 GB/s         | 3.0ns/667 MT/s             | 5-5-5                                                   | 4.0 GT/s           |

**Table 4: Part Numbers and Timing Parameters – 4GB**

Base device: MT47H256M4,<sup>1</sup> 1Gb DDR2 SDRAM

| Part Number <sup>2</sup> | Module Density | Configuration | Module Bandwidth | Memory Clock/<br>Data Rate | Clock Cycles<br>(CL- <sup>t</sup> RCD- <sup>t</sup> RP) | Link Transfer Rate |
|--------------------------|----------------|---------------|------------------|----------------------------|---------------------------------------------------------|--------------------|
| MT36HTF51272FZ-80E__     | 4GB            | 512 Meg x 72  | 6.4 GB/s         | 2.5ns/800 MT/s             | 5-5-5                                                   | 4.8 GT/s           |
| MT36HTF51272FZ-667__     | 4GB            | 512 Meg x 72  | 5.3 GB/s         | 3.0ns/667 MT/s             | 5-5-5                                                   | 4.0 GT/s           |

- Notes:
1. The data sheet for the base device can be found on Micron's Web site.
  2. All part numbers end with a four-place code (not shown) that designates component, PCB, and AMB revisions. Consult factory for current revision codes. Example: MT36HTF51272FZ-80EM1D6.

## Pin Assignments and Descriptions

**Table 5: Pin Assignments**

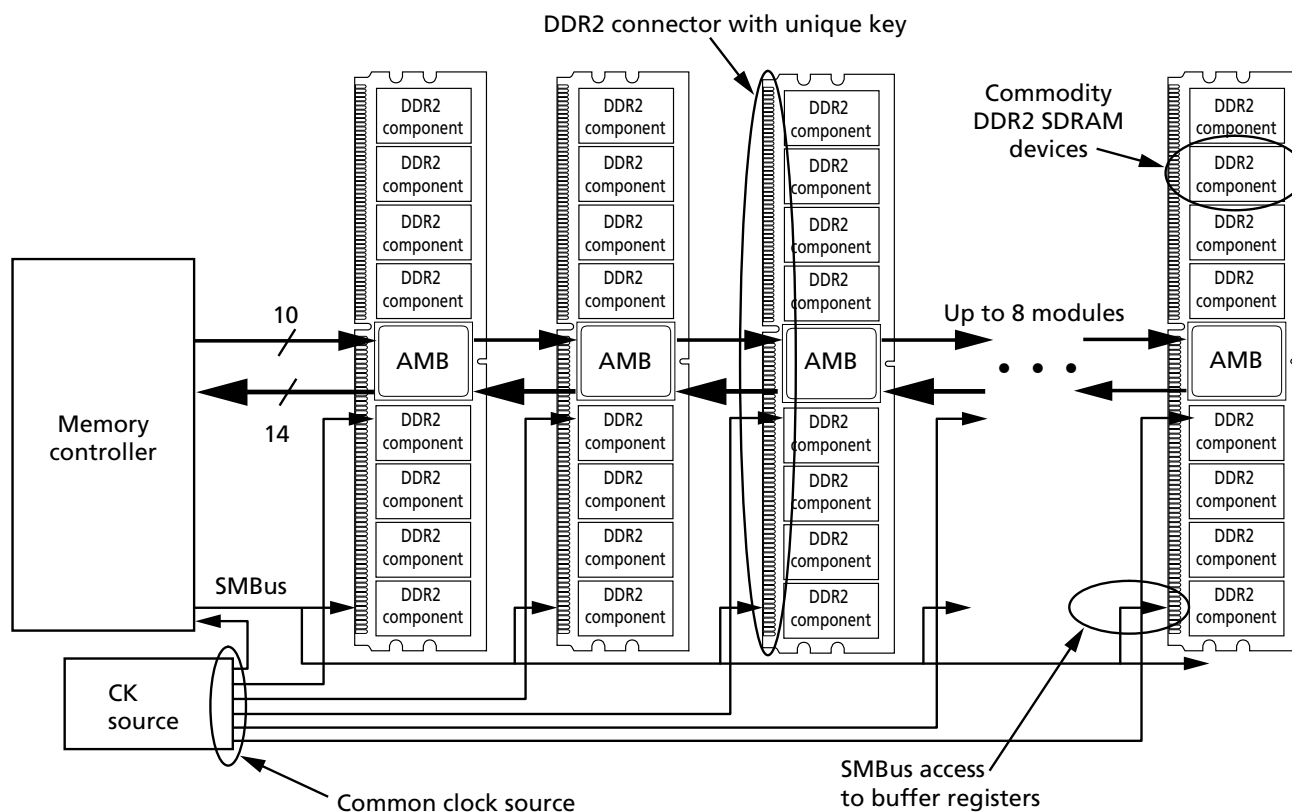
| 240-Pin DDR2 FBDIMM Front |                 |     |                    |     |                  |     |                   | 240-Pin DDR2 FBDIMM Back |                 |     |                    |     |                  |     |                    |
|---------------------------|-----------------|-----|--------------------|-----|------------------|-----|-------------------|--------------------------|-----------------|-----|--------------------|-----|------------------|-----|--------------------|
| Pin                       | Symbol          | Pin | Symbol             | Pin | Symbol           | Pin | Symbol            | Pin                      | Symbol          | Pin | Symbol             | Pin | Symbol           | Pin | Symbol             |
| 1                         | V <sub>DD</sub> | 31  | PN3                | 61  | PN9#             | 91  | PS9# <sup>1</sup> | 121                      | V <sub>DD</sub> | 151 | SN3                | 181 | SN9#             | 211 | SS9# <sup>1</sup>  |
| 2                         | V <sub>DD</sub> | 32  | PN3#               | 62  | V <sub>SS</sub>  | 92  | V <sub>SS</sub>   | 122                      | V <sub>DD</sub> | 152 | SN3#               | 182 | V <sub>SS</sub>  | 212 | V <sub>SS</sub>    |
| 3                         | V <sub>DD</sub> | 33  | V <sub>SS</sub>    | 63  | PN10             | 93  | PS5               | 123                      | V <sub>DD</sub> | 153 | V <sub>SS</sub>    | 183 | SN10             | 213 | SS5                |
| 4                         | V <sub>SS</sub> | 34  | PN4                | 64  | PN10#            | 94  | PS5#              | 124                      | V <sub>SS</sub> | 154 | SN4                | 184 | SN10#            | 214 | SS5#               |
| 5                         | V <sub>DD</sub> | 35  | PN4#               | 65  | V <sub>SS</sub>  | 95  | V <sub>SS</sub>   | 125                      | V <sub>DD</sub> | 155 | SN4#               | 185 | V <sub>SS</sub>  | 215 | V <sub>SS</sub>    |
| 6                         | V <sub>DD</sub> | 36  | V <sub>SS</sub>    | 66  | PN11             | 96  | PS6               | 126                      | V <sub>DD</sub> | 156 | V <sub>SS</sub>    | 186 | SN11             | 216 | SS6                |
| 7                         | V <sub>DD</sub> | 37  | PN5                | 67  | PN11#            | 97  | PS6#              | 127                      | V <sub>DD</sub> | 157 | SN5                | 187 | SN11#            | 217 | SS6#               |
| 8                         | V <sub>SS</sub> | 38  | PN5#               | 68  | V <sub>SS</sub>  | 98  | V <sub>SS</sub>   | 128                      | V <sub>SS</sub> | 158 | SN5#               | 188 | V <sub>SS</sub>  | 218 | V <sub>SS</sub>    |
| 9                         | V <sub>CC</sub> | 39  | V <sub>SS</sub>    | 69  | V <sub>SS</sub>  | 99  | PS7               | 129                      | V <sub>CC</sub> | 159 | V <sub>SS</sub>    | 189 | V <sub>SS</sub>  | 219 | SS7                |
| 10                        | V <sub>CC</sub> | 40  | PN13 <sup>1</sup>  | 70  | PS0              | 100 | PS7#              | 130                      | V <sub>CC</sub> | 160 | SN13 <sup>1</sup>  | 190 | SS0              | 220 | SS7#               |
| 11                        | V <sub>SS</sub> | 41  | PN13# <sup>1</sup> | 71  | PS0#             | 101 | V <sub>SS</sub>   | 131                      | V <sub>SS</sub> | 161 | SN13# <sup>1</sup> | 191 | SS0#             | 221 | V <sub>SS</sub>    |
| 12                        | V <sub>CC</sub> | 42  | V <sub>SS</sub>    | 72  | V <sub>SS</sub>  | 102 | PS8               | 132                      | V <sub>CC</sub> | 162 | V <sub>SS</sub>    | 192 | V <sub>SS</sub>  | 222 | SS8                |
| 13                        | V <sub>CC</sub> | 43  | V <sub>SS</sub>    | 73  | PS1              | 103 | PS8#              | 133                      | V <sub>CC</sub> | 163 | V <sub>SS</sub>    | 193 | SS1              | 223 | SS8#               |
| 14                        | V <sub>SS</sub> | 44  | DNU                | 74  | PS1#             | 104 | V <sub>SS</sub>   | 134                      | V <sub>SS</sub> | 164 | DNU                | 194 | SS1#             | 224 | V <sub>SS</sub>    |
| 15                        | V <sub>TT</sub> | 45  | DNU                | 75  | V <sub>SS</sub>  | 105 | DNU               | 135                      | V <sub>TT</sub> | 165 | DNU                | 195 | V <sub>SS</sub>  | 225 | DNU                |
| 16                        | DNU             | 46  | V <sub>SS</sub>    | 76  | PS2              | 106 | DNU               | 136                      | DNU             | 166 | V <sub>SS</sub>    | 196 | SS2              | 226 | DNU                |
| 17                        | RESET#          | 47  | V <sub>SS</sub>    | 77  | PS2#             | 107 | V <sub>SS</sub>   | 137                      | M_TEST<br>(DNU) | 167 | V <sub>SS</sub>    | 197 | SS2#             | 227 | V <sub>SS</sub>    |
| 18                        | V <sub>SS</sub> | 48  | PN12 <sup>1</sup>  | 78  | V <sub>SS</sub>  | 108 | V <sub>DD</sub>   | 138                      | V <sub>SS</sub> | 168 | SN12 <sup>1</sup>  | 198 | V <sub>SS</sub>  | 228 | SCK                |
| 19                        | DNU             | 49  | PN12# <sup>1</sup> | 79  | PS3              | 109 | V <sub>DD</sub>   | 139                      | DNU             | 169 | SN12# <sup>1</sup> | 199 | SS3              | 229 | SCK#               |
| 20                        | DNU             | 50  | V <sub>SS</sub>    | 80  | PS3#             | 110 | V <sub>SS</sub>   | 140                      | DNU             | 170 | V <sub>SS</sub>    | 200 | SS3#             | 230 | V <sub>SS</sub>    |
| 21                        | V <sub>SS</sub> | 51  | PN6                | 81  | V <sub>SS</sub>  | 111 | V <sub>DD</sub>   | 141                      | V <sub>SS</sub> | 171 | SN6                | 201 | V <sub>SS</sub>  | 231 | V <sub>DD</sub>    |
| 22                        | PN0             | 52  | PN6#               | 82  | PS4              | 112 | V <sub>DD</sub>   | 142                      | SN0             | 172 | SN6#               | 202 | SS4              | 232 | V <sub>DD</sub>    |
| 23                        | PN0#            | 53  | V <sub>SS</sub>    | 83  | PS4#             | 113 | V <sub>DD</sub>   | 143                      | SN0#            | 173 | V <sub>SS</sub>    | 203 | SS4#             | 233 | V <sub>DD</sub>    |
| 24                        | V <sub>SS</sub> | 54  | PN7                | 84  | V <sub>SS</sub>  | 114 | V <sub>SS</sub>   | 144                      | V <sub>SS</sub> | 174 | SN7                | 204 | V <sub>SS</sub>  | 234 | V <sub>SS</sub>    |
| 25                        | PN1             | 55  | PN7#               | 85  | V <sub>SS</sub>  | 115 | V <sub>DD</sub>   | 145                      | SN1             | 175 | SN7#               | 205 | V <sub>SS</sub>  | 235 | V <sub>DD</sub>    |
| 26                        | PN1#            | 56  | V <sub>SS</sub>    | 86  | DNU              | 116 | V <sub>DD</sub>   | 146                      | SN1#            | 176 | V <sub>SS</sub>    | 206 | DNU              | 236 | V <sub>DD</sub>    |
| 27                        | V <sub>SS</sub> | 57  | PN8                | 87  | DNU              | 117 | V <sub>TT</sub>   | 147                      | V <sub>SS</sub> | 177 | SN8                | 207 | DNU              | 237 | V <sub>TT</sub>    |
| 28                        | PN2             | 58  | PN8#               | 88  | V <sub>SS</sub>  | 118 | SA2               | 148                      | SN2             | 178 | SN8#               | 208 | V <sub>SS</sub>  | 238 | V <sub>DDSPD</sub> |
| 29                        | PN2#            | 59  | V <sub>SS</sub>    | 89  | V <sub>SS</sub>  | 119 | SDA               | 149                      | SN2#            | 179 | V <sub>SS</sub>    | 209 | V <sub>SS</sub>  | 239 | SA0                |
| 30                        | V <sub>SS</sub> | 60  | PN9                | 90  | PS9 <sup>1</sup> | 120 | SCL               | 150                      | V <sub>SS</sub> | 180 | SN9                | 210 | SS9 <sup>1</sup> | 240 | SA1                |

Note: 1. The following signals are cyclical redundancy code (CRC) bits and thus appear out of the normal sequence: PN12/PN12#, SN12/SN12#, PN13/PN13#, SN13/SN13#, PS9/PS9#, and SS9/SS9#.

**Table 6: Pin Descriptions**

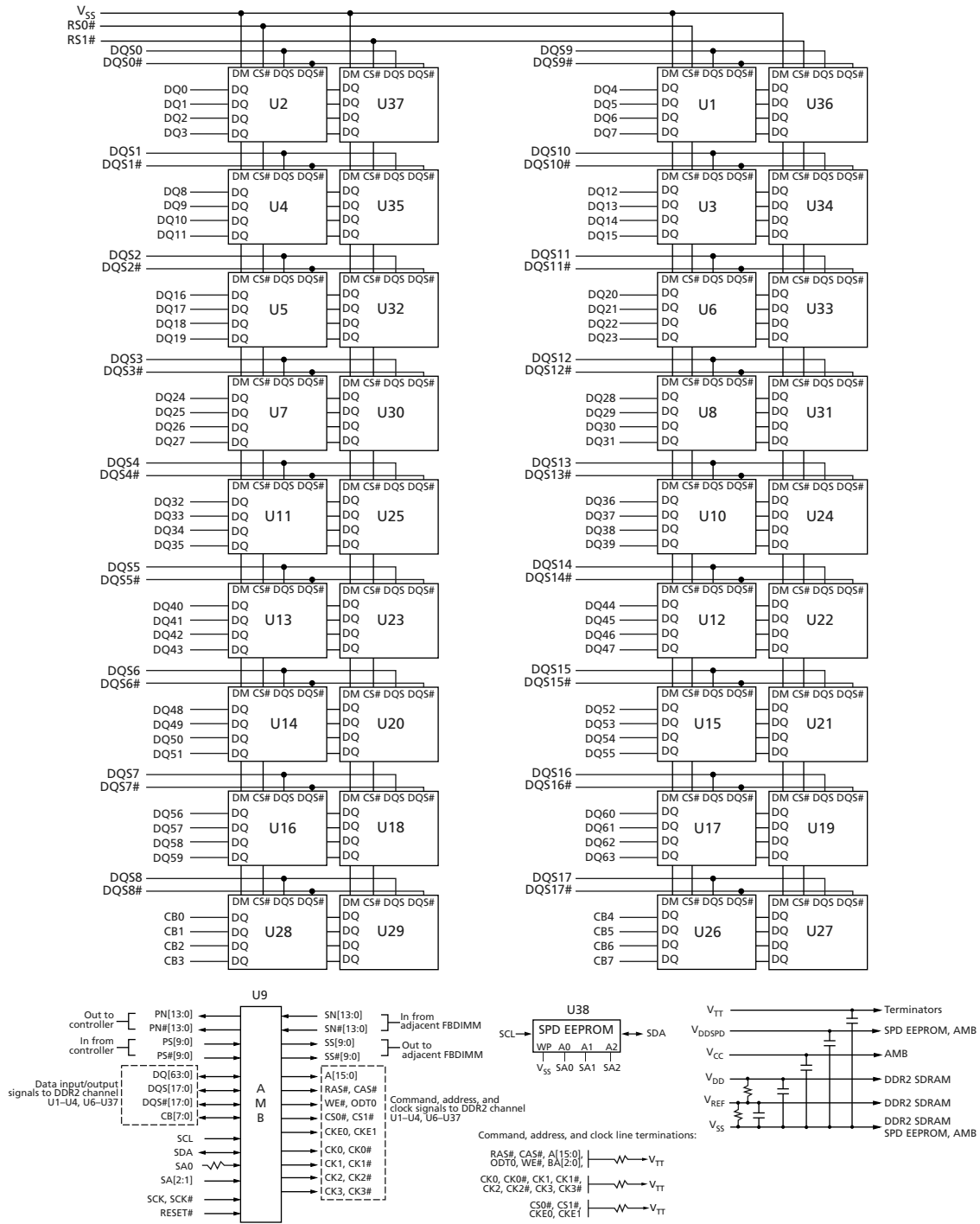
| Symbol      | Type   | Description                                                                                                                                                                                                                                                                                                                                                            |
|-------------|--------|------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|
| PS[9:0]     | Input  | Primary southbound data, positive lines.                                                                                                                                                                                                                                                                                                                               |
| PS#[9:0]    | Input  | Primary southbound data, negative lines.                                                                                                                                                                                                                                                                                                                               |
| SCK         | Input  | System clock input, positive line.                                                                                                                                                                                                                                                                                                                                     |
| SCK#        | Input  | System clock input, negative line.                                                                                                                                                                                                                                                                                                                                     |
| SCL         | Input  | Serial presence-detect (SPD) clock input.                                                                                                                                                                                                                                                                                                                              |
| SS[9:0]     | Input  | Secondary southbound data, positive lines.                                                                                                                                                                                                                                                                                                                             |
| SS#[9:0]    | Input  | Secondary southbound data, negative lines.                                                                                                                                                                                                                                                                                                                             |
| PN[13:0]    | Output | Primary northbound data, positive lines.                                                                                                                                                                                                                                                                                                                               |
| PN#[13:0]   | Output | Primary northbound data, negative lines.                                                                                                                                                                                                                                                                                                                               |
| SN[13:0]    | Output | Secondary northbound data, positive lines.                                                                                                                                                                                                                                                                                                                             |
| SN#[13:0]   | Output | Secondary northbound data, negative lines.                                                                                                                                                                                                                                                                                                                             |
| VID0        | Output | Voltage identification, connected to $V_{SS}$ . Indicates 1.5V DRAM present on module.                                                                                                                                                                                                                                                                                 |
| SA[2:0]     | I/O    | SPD address inputs, also used to select the FBDIMM number in the AMB.                                                                                                                                                                                                                                                                                                  |
| SDA         | I/O    | SPD data input/output.                                                                                                                                                                                                                                                                                                                                                 |
| RESET#      | Supply | AMB reset signal.                                                                                                                                                                                                                                                                                                                                                      |
| $V_{CC}$    | Supply | AMB core power and AMB channel interface power (1.5V).                                                                                                                                                                                                                                                                                                                 |
| $V_{DD}$    | Supply | DRAM power and AMB DRAM I/O power (1.5V).                                                                                                                                                                                                                                                                                                                              |
| $V_{TT}$    | Supply | DRAM clock, command, and address termination power ( $V_{DD}/2$ ).                                                                                                                                                                                                                                                                                                     |
| $V_{DDSPD}$ | Supply | SPD/AMB SMBus power.                                                                                                                                                                                                                                                                                                                                                   |
| $V_{SS}$    | Supply | Ground.                                                                                                                                                                                                                                                                                                                                                                |
| M_TEST      | –      | The M_TEST pin provides an external connection for testing the margin of $V_{REF}$ , which is produced by a voltage divider on the module. It is not intended to be used in normal system operation and must not be connected (DNU) in a system. This test pin may have other features on future card designs and will be included in this specification at that time. |
| DNU         | –      | Do not use.                                                                                                                                                                                                                                                                                                                                                            |

### Figure 2: System Block Diagram



### Functional Block Diagram

Figure 3: Functional Block Diagram



## General Description

Micron's FBDIMM devices adhere to the currently proposed industry specifications for FBDIMMs. The following specifications contain detailed information on FBDIMM design, interfaces, and theory of operation and are listed here for the system designers' convenience. Refer to the JEDEC Web site for available specifications.

- FBDIMM Design Specification – pending JEDEC approval
- FBDIMM: Architecture and Protocol – JESD206
- FBDIMM: Advanced Memory Buffer (AMB) – JESD82-20
- Design for Test, Design for Validation (DFx) Specification
- Serial Presence-Detect (SPD) for Fully Buffered DIMM – JEDEC Standard No. 21-C, page 4.1.2.7-1

This DDR2 SDRAM module is a high-bandwidth, large-capacity channel solution that has a narrow host interface. FBDIMM devices use DDR2 SDRAM devices isolated from the channel behind an AMB on the FBDIMM. Memory device capacity remains high, and total memory capacity scales with DDR2 SDRAM bit density.

As shown in the System Block Diagram, the FBDIMM channel provides a communication path from a host controller to an array of DDR2 SDRAM devices, with the DDR2 SDRAM devices buffered behind an AMB device. The physical isolation of the DDR2 SDRAM devices from the channel enhances the communication path and significantly increases the reliability and availability of the memory subsystem.

## Advanced Memory Buffer

The AMB isolates the DDR2 SDRAM devices from the channel. This single-chip AMB component, located in the center of each FBDIMM, acts as a repeater and buffer for all signals and commands exchanged between the host controller and DDR2 SDRAM devices, including data input and output. The AMB communicates with the host controller and adjacent FBDIMMs on a system board using an industry-standard, high-speed, differential, 1.5V, point-to-point interface. The AMB also enables buffering of memory traffic to support large memory capacities. Refer to the JEDEC JESD82-20 specification for further information.

## Electrical Specifications

Stresses greater than those listed may cause permanent damage to the module. This is a stress rating only, and functional operation of the module at these or any other conditions outside those indicated in the device data sheet is not implied. Exposure to absolute maximum rating conditions for extended periods may adversely affect reliability.

**Table 7: Absolute Maximum Ratings**

| Parameter                                    | Symbol            | Min  | Max   | Units | Notes |
|----------------------------------------------|-------------------|------|-------|-------|-------|
| Voltage on any pin relative to $V_{SS}$      | $V_{IN}, V_{OUT}$ | -0.3 | +1.75 | V     | 1     |
| Voltage on $V_{CC}$ pin relative to $V_{SS}$ | $V_{CC}$          | -0.3 | +1.75 | V     |       |
| Voltage on $V_{DD}$ pin relative to $V_{SS}$ | $V_{DD}$          | -0.5 | +2.3  | V     |       |
| Voltage on $V_{TT}$ pin relative to $V_{SS}$ | $V_{TT}$          | -0.5 | +2.3  | V     |       |
| DDR2 SDRAM device operating case temperature | $T_C$             | 0    | +95   | °C    | 2, 3  |
| AMB device operating temperature             |                   | 0    | +110  | °C    |       |

- Notes:
1.  $V_{IN}$  should not be greater than  $V_{CC}$ .
  2.  $T_C$  is specified at 95°C only when using 2X refresh timing ( $t_{REFI} = 7.8\mu s$  at or below 85°C;  $t_{REFI} = 3.9\mu s$  above 85°C); refer to the DDR2 SDRAM component data sheet.
  3. See applicable DDR2 SDRAM component data sheet for  $t_{REFI}$  and extended mode register settings. The  $t_{REFI}$  parameter is used to specify the doubled refresh interval necessary to sustain <85°C operation.

**Table 8: Input DC Voltage and Operating Conditions**

| Parameter                          | Symbol       | Min                  | Nom                 | Max                  | Units   | Notes |
|------------------------------------|--------------|----------------------|---------------------|----------------------|---------|-------|
| AMB supply voltage                 | $V_{CC}$     | 1.46                 | 1.5                 | 1.54                 | V       |       |
| DDR2 SDRAM supply voltage          | $V_{DD}$     | 1.7                  | 1.8                 | 1.9                  | V       |       |
| Termination voltage                | $V_{TT}$     | $0.48 \times V_{DD}$ | $0.5 \times V_{DD}$ | $0.52 \times V_{DD}$ | V       |       |
| EEPROM supply voltage              | $V_{DDSPD}$  | 3                    | 3.3                 | 3.6                  | V       | 1     |
| SPD input high (logic 1) voltage   | $V_{IH(DC)}$ | 2.1                  | —                   | $V_{DDSPD}$          | V       | 2     |
| SPD input low (logic 0) voltage    | $V_{IL(DC)}$ | —                    | —                   | 0.8                  | V       | 2     |
| RESET input high (logic 1) voltage | $V_{IH(DC)}$ | 1                    | —                   | —                    | V       | 3     |
| RESET input low (logic 0) voltage  | $V_{IL(DC)}$ | —                    | —                   | 0.5                  | V       | 2     |
| Leakage current (RESET)            | $I_L$        | -90                  | —                   | +90                  | $\mu A$ | 3     |
| Leakage current (link)             | $I_L$        | -5                   | —                   | +5                   | $\mu A$ | 4     |

- Notes:
1. Applies to AMB and SPD.
  2. Applies to serial memory buffer (SMB) and SPD bus signals.
  3. Applies to AMB CMOS signal RESET#.
  4. For all other AMB-related DC parameters, please refer to the high-speed differential link interface specification.



## 2GB, 4GB (x72, DR) 240-Pin DDR2 SDRAM FBDIMM Electrical Specifications

**Table 9: Clock Rates**

| FBDIMM Link Data Rate | Reference Clock | DRAM Clock | DRAM Data Rate |
|-----------------------|-----------------|------------|----------------|
| 3.2 Gb/s              | 133 MHz         | 266 MHz    | 533 Mb/s       |
| 4.0 Gb/s              | 167 MHz         | 333 MHz    | 666 Mb/s       |
| 4.8 Gb/s              | 200 MHz         | 400 MHz    | 800 Mb/s       |

Note: 1. DDR2 components may exceed the listed module speed grades; module may not be available in all listed speed grades

## IDD Specifications and Conditions

**Table 10: I<sub>DD</sub> Conditions**

| Symbol                   | Condition                                                                                                                                                                                                                 |
|--------------------------|---------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|
| I <sub>DD_IDLE_0</sub>   | <b>Idle current, single, or last DIMM:</b> L0 state; Idle (0% bandwidth); Primary channel enabled; Secondary channel disabled; CKE HIGH; Command and address lines stable; DDR2 SDRAM clock active                        |
| I <sub>DD_IDLE_1</sub>   | <b>Idle current, first DIMM:</b> L0 state; Idle (0% bandwidth); Primary and secondary channels enabled; CKE HIGH; Command and address lines stable; DDR2 SDRAM clock active                                               |
| I <sub>DD_ACTIVE_1</sub> | <b>Active power:</b> L0 state; 50% DRAM bandwidth; 67% READ; 33% WRITE; Primary and secondary channels enabled; DDR2 SDRAM clock active; CKE HIGH                                                                         |
| I <sub>DD_ACTIVE_2</sub> | <b>Active power, data pass through:</b> L0 state; 50% DRAM bandwidth to downstream DIMM; 67% READ; 33% WRITE; Primary and secondary channels enabled; DDR2 SDRAM clock active; CKE HIGH; Command and address lines stable |
| I <sub>DD_TRAINING</sub> | <b>Training:</b> Primary and secondary channels enabled; 100% toggle on all channel lanes; DRAMs idle; 0% bandwidth; CKE HIGH; Command and address lines stable; DDR2 SDRAM clock active                                  |
| I <sub>DD_IBIST</sub>    | <b>IBIST over all IBIST modes:</b> DRAM idle (0% bandwidth); Primary channel enabled; Secondary channel enabled; CKE HIGH; Command and address lines stable; DDR2 SDRAM clock active                                      |
| I <sub>DD_EI</sub>       | <b>Electrical idle:</b> DRAM idle (0% bandwidth); Primary channel disabled; Secondary channel disabled; CKE LOW; Command and address lines floated; DDR2 SDRAM clock active; ODT and CKE driven LOW                       |

Note: 1. Actual test conditions may vary from published JEDEC test conditions.

**Table 11: I<sub>DD</sub> Specifications – All Densities DDR2-800**

| Symbol          | I <sub>DD_IDLE_0</sub> | I <sub>DD_IDLE_1</sub> | I <sub>DD_ACTIVE_1</sub> | I <sub>DD_ACTIVE_2</sub> | I <sub>DD_TRAINING</sub> | I <sub>DD_IBIST</sub> | I <sub>DD_EI</sub> | Units |
|-----------------|------------------------|------------------------|--------------------------|--------------------------|--------------------------|-----------------------|--------------------|-------|
| I <sub>CC</sub> | TBD                    | TBD                    | TBD                      | TBD                      | TBD                      | TBD                   | TBD                | mA    |
| I <sub>DD</sub> | TBD                    | TBD                    | TBD                      | TBD                      | TBD                      | TBD                   | TBD                | mA    |
| Total power     | TBD                    | TBD                    | TBD                      | TBD                      | TBD                      | TBD                   | TBD                | W     |

**Table 12: I<sub>DD</sub> Specifications – 2GB DDR2-667**

| Symbol          | I <sub>DD_IDLE_0</sub> | I <sub>DD_IDLE_1</sub> | I <sub>DD_ACTIVE_1</sub> | I <sub>DD_ACTIVE_2</sub> | I <sub>DD_TRAINING</sub> | I <sub>DD_IBIST</sub> | I <sub>DD_EI</sub> | Units |
|-----------------|------------------------|------------------------|--------------------------|--------------------------|--------------------------|-----------------------|--------------------|-------|
| I <sub>CC</sub> | 2600                   | 3400                   | 3900                     | 3700                     | 4000                     | 4500                  | 2500               | mA    |
| I <sub>DD</sub> | 2520                   | 2520                   | 4655                     | 2520                     | 2520                     | 2520                  | 452                | mA    |
| Total power     | 8.8                    | 10.1                   | 15                       | 10.6                     | 11.1                     | 1.9                   | 4.8                | W     |

**Table 13: I<sub>DD</sub> Specifications – 4GB DDR2-667 (Die Rev H)**

| Symbol          | I <sub>DD_IDLE_0</sub> | I <sub>DD_IDLE_1</sub> | I <sub>DD_ACTIVE_1</sub> | I <sub>DD_ACTIVE_2</sub> | I <sub>DD_TRAINING</sub> | I <sub>DD_IBIST</sub> | I <sub>DD_EI</sub> | Units |
|-----------------|------------------------|------------------------|--------------------------|--------------------------|--------------------------|-----------------------|--------------------|-------|
| I <sub>CC</sub> | 2600                   | 3400                   | 3900                     | 3700                     | 4000                     | 4500                  | 2500               | mA    |
| I <sub>DD</sub> | 1764                   | 1764                   | 3422                     | 1764                     | 1764                     | 1764                  | 452                | mA    |



Table 13: I<sub>DD</sub> Specifications – 4GB DDR2-667 (Die Rev H) (Continued)

| Symbol      | I <sub>DD_IDLE_0</sub> | I <sub>DD_IDLE_1</sub> | I <sub>DD_ACTIVE_1</sub> | I <sub>DD_ACTIVE_2</sub> | I <sub>DD_TRAINING</sub> | I <sub>DD_IBIST</sub> | I <sub>DD_EI</sub> | Units |
|-------------|------------------------|------------------------|--------------------------|--------------------------|--------------------------|-----------------------|--------------------|-------|
| Total power | 7.4                    | 8.7                    | 12.6                     | 9.2                      | 9.6                      | 10.4                  | 4.8                | W     |

Table 14: I<sub>DD</sub> Specifications – 4GB DDR2-667 (Die Rev M)

| Symbol          | I <sub>DD_IDLE_0</sub> | I <sub>DD_IDLE_1</sub> | I <sub>DD_ACTIVE_1</sub> | I <sub>DD_ACTIVE_2</sub> | I <sub>DD_TRAINING</sub> | I <sub>DD_IBIST</sub> | I <sub>DD_EI</sub> | Units |
|-----------------|------------------------|------------------------|--------------------------|--------------------------|--------------------------|-----------------------|--------------------|-------|
| I <sub>CC</sub> | 2600                   | 3400                   | 3900                     | 3700                     | 4000                     | 4500                  | 2500               | mA    |
| I <sub>DD</sub> | 1764                   | 1764                   | 3422                     | 1764                     | 1764                     | 1764                  | 560                | mA    |
| Total power     | 7.4                    | 8.7                    | 12.6                     | 9.2                      | 9.6                      | 10.4                  | 5.0                | W     |

## Serial Presence-Detect

For the latest SPD data, refer to Micron's SPD page: [www.micron.com/SPD](http://www.micron.com/SPD).

Table 15: Serial Presence-Detect EEPROM DC Operating Conditions

| Parameter/Condition                                               | Symbol             | Min                      | Max                      | Units |
|-------------------------------------------------------------------|--------------------|--------------------------|--------------------------|-------|
| EEPROM and AMB supply voltage                                     | V <sub>DDSPD</sub> | 3                        | 3.6                      | V     |
| Input high voltage: Logic 1; all inputs                           | V <sub>IH</sub>    | V <sub>DDSPD</sub> × 0.7 | V <sub>DDSPD</sub> + 0.5 | V     |
| Input low voltage: Logic 0; all inputs                            | V <sub>IL</sub>    | −0.6                     | V <sub>DDSPD</sub> × 0.3 | V     |
| Output low voltage: I <sub>OUT</sub> = 3mA                        | V <sub>OL</sub>    | −                        | 0.4                      | V     |
| Input leakage current: V <sub>IN</sub> = GND to V <sub>DD</sub>   | I <sub>LI</sub>    | 0.10                     | 3                        | μA    |
| Output leakage current: V <sub>OUT</sub> = GND to V <sub>DD</sub> | I <sub>LO</sub>    | 0.05                     | 3                        | μA    |
| Standby current                                                   | I <sub>SB</sub>    | 1.6                      | 4                        | μA    |
| Power supply current, READ: SCL clock frequency = 100 kHz         | I <sub>CCR</sub>   | 0.4                      | 1                        | mA    |
| Power supply current, WRITE: SCL clock frequency = 100 kHz        | I <sub>CCW</sub>   | 2                        | 3                        | mA    |

Table 16: Serial Presence-Detect EEPROM AC Operating Conditions

| Parameter/Condition                                         | Symbol              | Min | Max | Units | Notes |
|-------------------------------------------------------------|---------------------|-----|-----|-------|-------|
| SCL LOW to SDA data-out valid                               | t <sub>AA</sub>     | 0.2 | 0.9 | μs    | 1     |
| Time the bus must be free before a new transition can start | t <sub>BUF</sub>    | 1.3 | −   | μs    |       |
| Data-out hold time                                          | t <sub>DH</sub>     | 200 | −   | ns    |       |
| SDA and SCL fall time                                       | t <sub>F</sub>      | −   | 300 | ns    | 2     |
| Data-in hold time                                           | t <sub>HD:DAT</sub> | 0   | −   | μs    |       |
| Start condition hold time                                   | t <sub>HD:STA</sub> | 0.6 | −   | μs    |       |
| Clock HIGH period                                           | t <sub>HIGH</sub>   | 0.6 | −   | μs    |       |
| Noise suppression time constant at SCL, SDA inputs          | t <sub>I</sub>      | −   | 50  | ns    |       |
| Clock LOW period                                            | t <sub>LOW</sub>    | 1.3 | −   | μs    |       |
| SDA and SCL rise time                                       | t <sub>R</sub>      | −   | 0.3 | μs    | 2     |
| SCL clock frequency                                         | f <sub>SCL</sub>    | −   | 400 | kHz   |       |

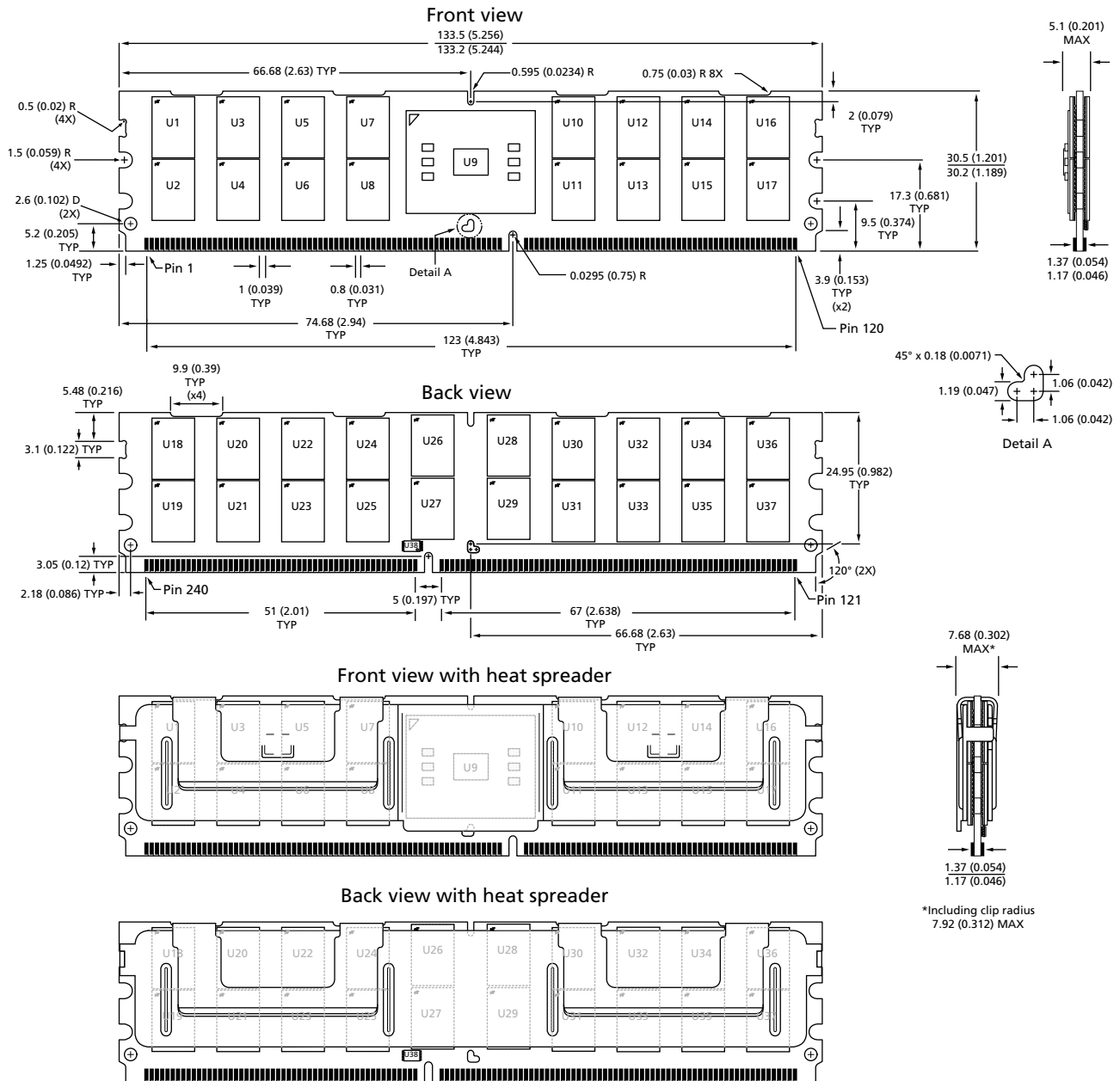
**Table 16: Serial Presence-Detect EEPROM AC Operating Conditions (Continued)**

| Parameter/Condition        | Symbol       | Min | Max | Units   | Notes |
|----------------------------|--------------|-----|-----|---------|-------|
| Data-in setup time         | $t_{SU:DAT}$ | 100 | –   | ns      |       |
| Start condition setup time | $t_{SU:STA}$ | 0.6 | –   | $\mu s$ | 3     |
| Stop condition setup time  | $t_{SU:STO}$ | 0.6 | –   | $\mu s$ |       |
| WRITE cycle time           | $t_{WRC}$    | –   | 10  | ms      | 4     |

- Notes:
1. To avoid spurious start and stop conditions, a minimum delay is placed between SCL = 1 and the falling or rising edge of SDA.
  2. This parameter is sampled.
  3. For a restart condition, or following a WRITE cycle.
  4. The SPD EEPROM WRITE cycle time ( $t_{WRC}$ ) is the time from a valid stop condition of a write sequence to the end of the EEPROM internal ERASE/PROGRAM cycle. During the WRITE cycle, the EEPROM bus interface circuit is disabled, SDA remains HIGH due to pull-up resistance, and the EEPROM does not respond to its slave address.

## Module Dimensions

**Figure 4: 240-Pin DDR2 FBDIMM**



- Notes: 1. All dimensions are in millimeters (inches); MAX/MIN or typical (TYP) where noted.  
2. The dimensional diagram is for reference only.



## 2GB, 4GB (x72, DR) 240-Pin DDR2 SDRAM FBDIMM Module Dimensions

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This data sheet contains minimum and maximum limits specified over the power supply and temperature range set forth herein.  
Although considered final, these specifications are subject to change, as further product development and data characterization some-  
times occur.